Substitute for form 1449A/PTO

INFORMATION DISCUSSION
STATEMENT BY APPLICANT

	Complete if Known
Application Number	09/934,791
Filing Date	August 21, 2001
First Named Inventor	Larry A. Coldren et al.
Art Unit	2881
Examiner Name	Not assigned

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(use as many sheets as necessary)

Sheet 1 of 1

			U.S. PATENT	DOCUMENTS	· · · · · · · ·
Examiner Initials*	Cite No.	Document Number Number -Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	1/2
pr	•	US-4,829,347	05/09/89	Cheng et al.	<u>`</u>
1		US-5,245,622	09/14/93	Jewell et al.	
		US-5,422,901	06/06/95	Lebby et al.	<u> </u>
-		US-5,693,180	12/02/97	Furukawa et al.	
		US-5,719,891	02/17/98	Jewell	
1,	<u> </u>	US-5,985,683	11/16/99	Jewell	
1		US-5,991,326	11/23/99	Yuen et al.	
	†	US-	<u> </u>		

Attorney Docket Number

		FORE	IGN PATENT DO	OCUMENTS	/•	
Examiner Initials*	Cite No.	Foreign Patent Document Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶

		OTHER PRIOR ART – NONPATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
pN		C. Starck, "Long Wavelength VCSEL with Tunnel Junction and Metamorphic A1As/GaAs Conductive DBR", LEOS '99: IEEE Lasers and Electro-Optics Society 1999 12 th Annual Meeting, November 1999, Vol. 1, pp. 139-140, especially Figure 1.	
pn!		K.D. Choquette et al., "Room Temperature Continuous Wave InGaAsN Quantum Well Vertical-Cavity Lasers Emitting at 1.3 μm", ELECTRONICS LETTERS, 03 August 2000, Vol. 36 No. 16, pp. 1388-1390.	

Examiner Signatur	Te PN	Date Considered 4/11/03	
			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of

Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is